

SHARP

PC419K

# PC419K

**Compact Surface Mounted,  
Bi-directional Linear  
Output Type Photocoupler**

## ■ Features

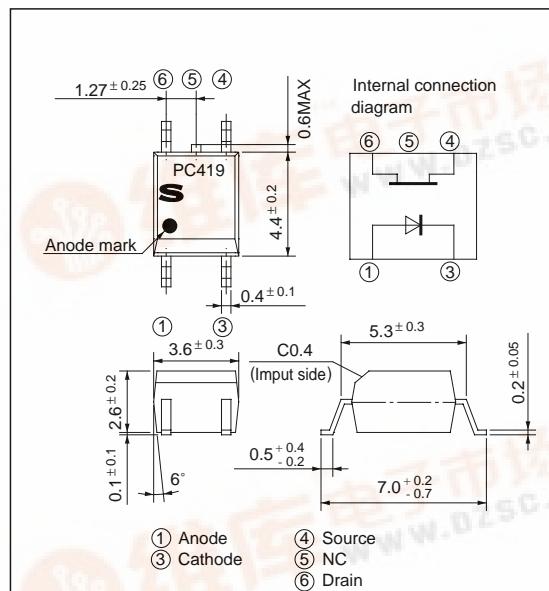
1. Bi-directional linear output
2. High breakdown voltage  
(  $V_{BR}$  : 120V )
3. Low collector dark current  
(  $I_d$  : MAX. 10nA )
4. High isolation voltage between input and output  
(  $V_{iso}$  : 3 750V<sub>rms</sub> )

## ■ Applications

1. Board testers
2. Programmable controllers
3. Analog switch
4. Hybrid substrates which require high density mounting

## ■ Outline Dimensions

( Unit : mm )



## ■ Package Specifications

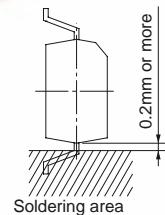
Model No.	Package specifications	Diameter of reel	Tape width
<b>PC419K</b>	Taping package (Net : 3 000pcs. )	φ 370mm	12mm
<b>PC419KT</b>	Taping package (Net : 750pcs. )	φ 178mm	12mm
<b>PC419KZ</b>	Sleeve package (Net : 100pcs. )	-	-

## ■ Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	mA
	Reverse voltage	V <sub>R</sub>	V
	* <sup>1</sup> Power dissipation	P	mW
Output	Output current	I <sub>O</sub>	mA
	Breakdown voltage	V <sub>BR</sub>	V
	* <sup>1</sup> Power dissipation	P <sub>O</sub>	mW
Total power dissipation	P <sub>tot</sub>	120	mW
* <sup>1</sup> Isolation voltage	V <sub>iso</sub>	3 750	V <sub>rms</sub>
Operating temperature	T <sub>opr</sub>	- 25 to + 100	°C
Storage temperature	T <sub>stg</sub>	- 40 to + 125	°C
* <sup>2</sup> Soldering temperature	T <sub>sol</sub>	260	°C

\*1 AC for 1 minute, 40 to 60% RH

\*2 10 seconds or less, 0.2mm or more from the root of lead.

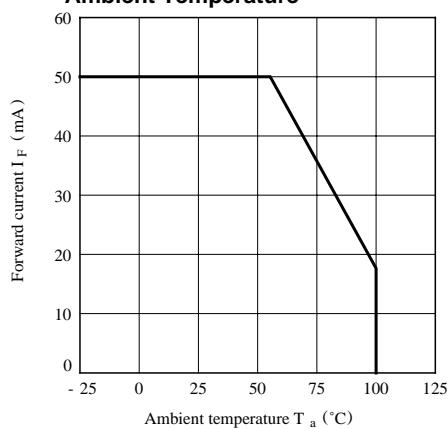
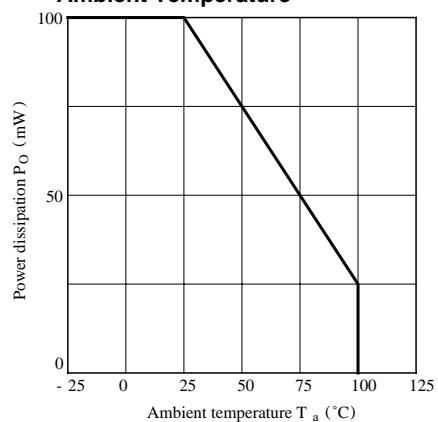


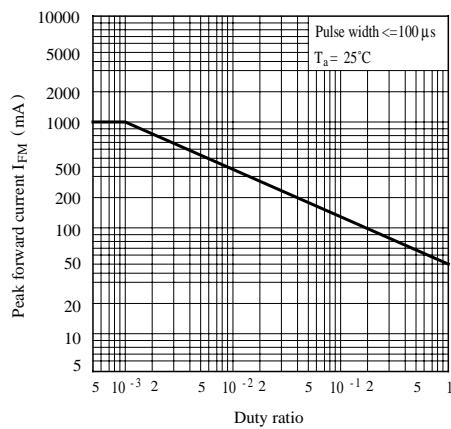
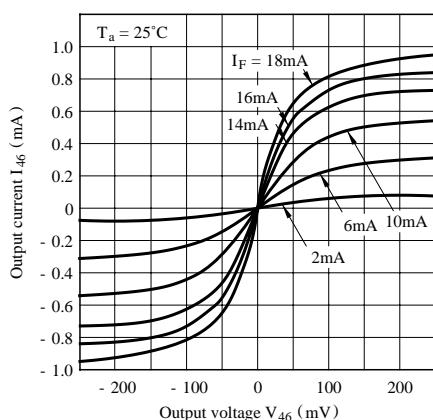
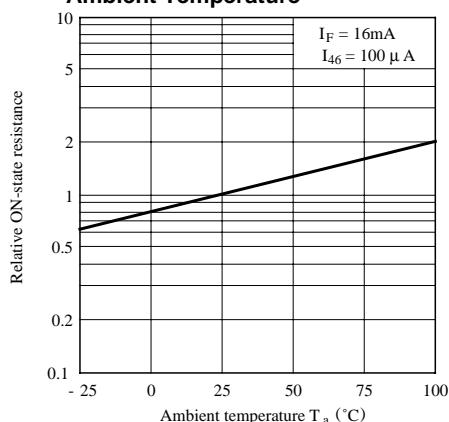
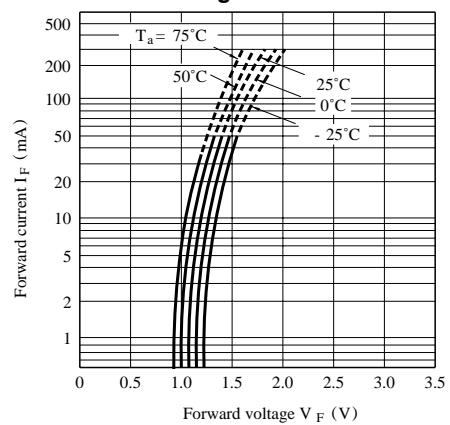
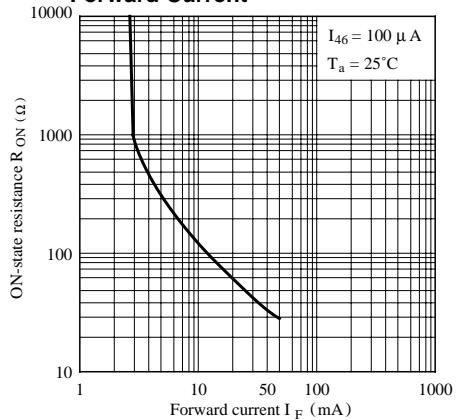
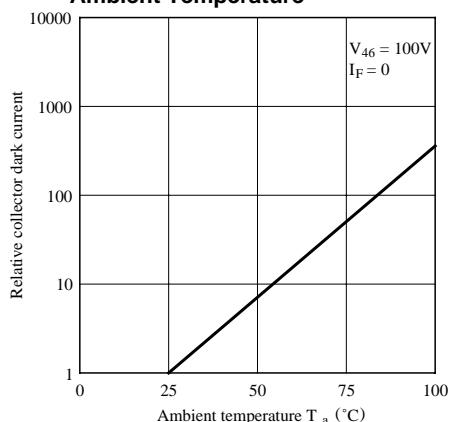
**■ Electro-optical Characteristics**

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 16mA	-	1.2	1.4	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 6V	-	-	10	μA
	Terminal capacitance	C <sub>t1</sub>	V = 0, f = 1kHz	-	50	250	pF
Output	* <sup>3</sup> Breakdown voltage	V <sub>BR</sub>	I <sub>46</sub> = 100 μA, I <sub>F</sub> = 0	120	-	-	V
	* <sup>3</sup> Collector dark current	I <sub>d</sub>	V <sub>46</sub> = 100V, I <sub>F</sub> = 0	-	-	10	nA
	* <sup>3</sup> OFF-state resistance	R <sub>OFF</sub>	V <sub>46</sub> = 100V, I <sub>F</sub> = 0	10 <sup>10</sup>	-	-	Ω
	Terminal capacitance	C <sub>t2</sub>	V <sub>46</sub> = 0, f = 1MHz	-	-	25	pF
Transfer characteristics	* <sup>3</sup> ON-state resistance	R <sub>ON</sub>	I <sub>F</sub> = 16mA, I <sub>46</sub> = 100 μA	-	-	200	Ω
	Isolation resistance	R <sub>ISO</sub>	DC500V, 40 to 60% RH	5 x 10 <sup>10</sup>	10 <sup>11</sup>	-	Ω
	Floating capacitance	C <sub>f</sub>	V = 0, f = 1MHz	-	-	2.5	pF
	Turn-on time	t <sub>on</sub>	I <sub>F</sub> = 16mA, V <sub>46</sub> = 5V	-	-	65	μs
	Turn-off time	t <sub>off</sub>	R <sub>L</sub> = 50Ω	-	-	65	

\*3 Applies to forward and reverse directions between terminals 4 and 6.

**Fig. 1 Forward Current vs.  
Ambient Temperature****Fig. 2 Power Dissipation vs.  
Ambient Temperature**

**Fig. 3 Peak Forward Current vs. Duty Ratio****Fig. 5 Output Current vs. Output Voltage****Fig. 7 Relative ON-state Resistance vs. Ambient Temperature****Fig. 4 Forward Current vs. Forward Voltage****Fig. 6 ON-state Resistance vs. Forward Current****Fig. 8 Relative Collector Dark Current vs. Ambient Temperature**

●Please refer to the chapter “Precautions for Use”.